L Number	Hits	Search Text	DB	Time stamp
2	4191	(372/43-50).CCLS.	USPAT	2003/08/14 13:03
3	2807	(372/49,9,50,108,101).CCLS.	USPAT	2003/08/14 13:03
5	1172	((372/49,9,50,108,101).CCLS.) and lens	USPAT	2003/08/14 13:04
4	881	((372/43-50).CCLS.) and lens	USPAT	2003/08/14 14:13
6	7	5966399.URPN.	USPAT	2003/08/14 13:50
7	2	("5426657" | "5838715").PN.	USPAT	2003/08/14 13:51
8	7	5553089.URPN.	USPAT	2003/08/14 14:03
9	3	("5081639" | "5086431" | "5212706").PN.	USPAT	2003/08/14 14:03
10	655	(((372/49,9,50,108,101).CCLS.) and lens) not (((372/43-50).CCLS.) and lens)	USPAT	2003/08/14 14:25
11	2483	372/43-50.ccls. and (ridge stripe mesa)	USPAT	2003/08/14 14:25
12	486	(372/43-50.ccls. and (ridge stripe mesa)) and lens	USPAT	2003/08/14 14:26
13	0	((372/43-50.ccls. and (ridge stripe mesa)) and lens) not (((((372/43-50).CCLS.) and lens) (((372/49,9,50,108,101).CCLS.) and lens))	USPAT	2003/08/14 14:30
14	1	6167070.pn.	USPAT	2003/08/14 14:31
15	1	6037189.pn.	USPAT	2003/08/14 15:02
16	1205	(372/43-50.ccls. and (ridge stripe mesa)) and (film passivation)	USPAT	2003/08/14 15:04
17	1165	372/46.ccls. and (stripe ridge)	USPAT	2003/08/14 15:04
18	666	(372/46.ccls. and (stripe ridge)) and (film passivation)	USPAT	2003/08/14 15:06
19	50	(372/46.ccls. and (stripe ridge)) and (passivation)	USPAT	2003/08/14 15:26
20	9	(372/46.ccls. and (stripe ridge)) and (SiO TiO) near3 (layer film)	USPAT	2003/08/14 15:26
21	26	(US-6463087-$ or US-6134368-$ or US-6374028-$ or US-6455342-$ or US-6327288-$ or US-6034983-$ or US-6219366-$ or US-6465269-$ or US-5790578-$ or US-5665985-$ or US-6586776-$ or US-6167070-$ or US-6122417-$ or US-6058125-$ or US-6037189-$ or US-5970081-$ or US-5966399-$ or US-5835517-$ or US-5553089-$ or US-5428227-$ or US-5457569-$ or US-6472691-$ or US-5659565-$ or US-5640410-$ or US-5333141-$ or US-4813054-$).did.	USPAT	2003/08/14 15:52

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L Number	Hits	Search Text	DB	Time stamp
1	4405	(semiconductor near3 laser) same (stripe ridge mesa)	USPAT; EPO; JPO; IBM_TDB	2003/08/12 15:27
2	2371	((semiconductor near3 laser) same (stripe ridge mesa)) and 372/$.ccls.	USPAT; EPO; JPO; IBM_TDB	2003/08/12 17:27
3	112	(((semiconductor near3 laser) same (stripe ridge mesa)) and 372/$.ccls.) and edge near2 emit$4	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:44
4	7	6324326.URPN.	USPAT	2003/08/12 18:20
5	18	("4161944" | "4179187" | "4212660" | "4705351" | "4886538" | "4901324" | "4941726" | "5119460" | "5166940" | "5265177" | "5422897" | "5455879" | "5530710" | "5659644" | "5710789" | "5774484" | "5864644" | "5940557").PN.	USPAT	2003/08/12 18:22
6	4	6134368.URPN.	USPAT	2003/08/12 18:31
7	4	("5284791" | "5360763" | "5382543" | "5717710").PN.	USPAT	2003/08/12 18:33
8	2	nichia.as. and (edge with emit$4) and laser	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:46
9	212	nichia.as. and laser	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:46
10	70	(nichia.as. and laser) and (ridge stripe)	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:50
11	11910	372/43-50.ccls.	USPAT; EPO; JPO; IBM_TDB	2003/08/12 19:18
12	665	372/43-50.ccls. and (edge with emit$5)	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:50
13	281	(372/43-50.ccls. and (edge with emit$5)) and (ridge stripe)	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:50
14	192	((372/43-50.ccls. and (edge with emit$5)) and (ridge stripe)) not ((((semiconductor near3 laser) same (stripe ridge mesa)) and 372/$.ccls.) and edge near2 emit$4)	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:51
15	80	(((372/43-50.ccls. and (edge with emit$5)) and (ridge stripe)) not ((((semiconductor near3 laser) same (stripe ridge mesa)) and 372/$.ccls.) and edge near2 emit$4)) and (film "Si0.sub.2" "TiO" "SiO")	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:52
16	1	(((372/43-50.ccls. and (edge with emit$5)) and (ridge stripe)) not ((((semiconductor near3 laser) same (stripe ridge mesa)) and 372/$.ccls.) and edge near2 emit$4)) and (shad$4 with film)	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:52
17	5	6034983.URPN.	USPAT	2003/08/12 19:01
18	13	("5011550" | "5079184" | "5130269" | "5227328" | "5229319" | "5266127" | "5300186" | "5399522" | "5424243" | "5574289" | "5657338" | "5787106" | "5790578").PN.	USPAT	2003/08/12 19:03
19	219	372/43-50.ccls. and (edge with emitting) and (stripe ridge) and active and semiconductor and substrate	USPAT; EPO; JPO; IBM_TDB	2003/08/12 19:40
20	2	372/43-50.ccls. and (edge with emitting) and (stripe ridge) and (shad$3 with film)	USPAT; EPO; JPO; IBM_TDB	2003/08/12 19:48

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